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Team Nexperia

74LVC162244A; 74LVCH162244A

16-bit buffer/line driver; 30 Ω series termination resistors; 5 V tolerant input/output; 3-state

Rev. 6 — 16 December 2011

Product data sheet

1. General description

The 74LVC162244A; 74LVCH162244A are 16-bit non-inverting buffer/line drivers with 3-state bus compatible outputs. The device can be used as four 4-bit buffers, two 8-bit buffers or one 16-bit buffer. It features four output enable inputs, ($\overline{1OE}$ to $\overline{4OE}$) each controlling four of the 3-state outputs. A HIGH on \overline{OE} causes the outputs to assume a high-impedance OFF-state. The device is designed with 30 Ω series termination resistors in both HIGH and LOW output stages to reduce line noise.

Inputs can be driven from either 3.3 V or 5 V devices. When disabled, up to 5.5 V can be applied to the outputs. These features allow the use of these devices in mixed 3.3 V and 5 V applications.

The 74LVCH162244A bus hold on data inputs eliminates the need for external pull-up resistors to hold unused inputs.

2. Features and benefits

- 5 V tolerant inputs/outputs for interfacing with 5 V logic
- Wide supply voltage range from 1.2 V to 3.6 V
- CMOS low power consumption
- Multibyte flow-through standard pin-out architecture
- Low inductance multiple power and ground pins for minimum noise and ground bounce
- Direct interface with TTL levels
- High-impedance when V_{CC} = 0 V
- All data inputs have bus hold. (74LVCH162244A only)
- Complies with JEDEC standard:
 - ◆ JESD8-7A (1.65 V to 1.95 V)
 - ◆ JESD8-5A (2.3 V to 2.7 V)
 - ◆ JESD8-C/JESD36 (2.7 V to 3.6 V)
- ESD protection:
 - HBM JESD22-A114F exceeds 2000 V
 - ♦ MM JESD22-A115-B exceeds 200 V
 - CDM JESD22-C101E exceeds 1000 V
- Specified from -40 °C to +85 °C and -40 °C to +125 °C

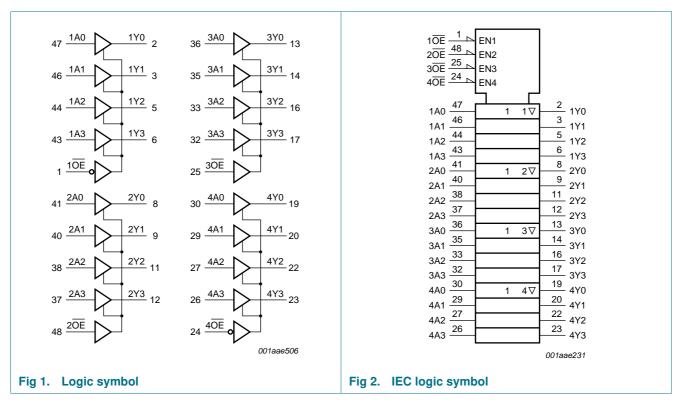


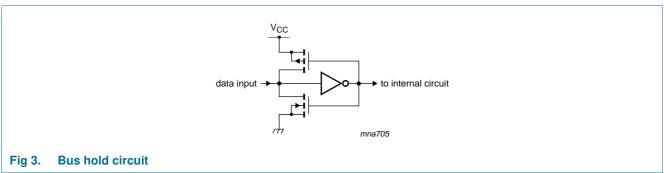
3. Ordering information

Table 1. Ordering information

Type number	Temperature range	Package					
		Name	Description	Version			
74LVC162244ADL	–40 °C to +125 °C	SSOP48	plastic shrink small outline package; 48 leads;	SOT370-1			
74LVCH162244ADL			body width 7.5 mm				
74LVC162244ADGG	–40 °C to +125 °C	TSSOP48	plastic thin shrink small outline package;	SOT362-1			
74LVCH162244ADGG			48 leads; body width 6.1 mm				

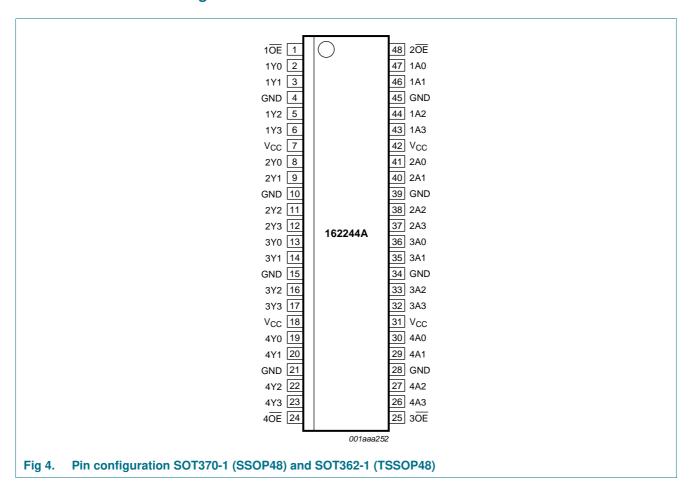
4. Functional diagram





5. Pinning information

5.1 Pinning



5.2 Pin description

Table 2. Pin description

Symbol	Pin	Description
1 OE	1	output enable input (active LOW)
2 OE	48	output enable input (active LOW)
3 OE	25	output enable input (active LOW)
4 OE	24	output enable input (active LOW)
GND	4, 10, 15, 21, 28, 34, 39, 45	ground (0 V)
V _{CC}	7, 18, 31, 42	supply voltage
1A[0:3]	47, 46, 44, 43	data input
2A[0:3]	41, 40, 38, 37	data input
3A[0:3]	36, 35, 33, 32	data input
4A[0:3]	30, 29, 27, 26	data input
1Y[0:3]	2, 3, 5, 6	data output

74LVC_LVCH162244A

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Table 2. Pin description ... continued

Symbol	Pin	Description
2Y[0:3]	8, 9, 11, 12	data output
3Y[0:3]	13, 14, 16, 17	data output
4Y[0:3]	19, 20, 22, 23	dataoutput

6. Functional description

Table 3. Function table[1]

Control	Input	Output
nOE	nAn	nYn
L	L	L
L	Н	Н
Н	X	Z

^[1] H = HIGH voltage level; L = LOW voltage level; X = don't care; Z = high-impedance OFF-state.

7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CC}	supply voltage		-0.5	+6.5	V
I _{IK}	input clamping current	$V_I < 0 V$	-50	-	mA
VI	input voltage		[<u>1]</u> -0.5	+6.5	V
l _{OK}	output clamping current	$V_O > V_{CC}$ or $V_O < 0 V$	-	±50	mA
V_O	output voltage	output HIGH or LOW	<u>[2]</u> –0.5	$V_{CC} + 0.5$	V
		output 3-state	<u>[2]</u> –0.5	+6.5	V
lo	output current	$V_O = 0 V \text{ to } V_{CC}$	-	±50	mA
I _{CC}	supply current		-	100	mA
I_{GND}	ground current		-100	-	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation	$T_{amb} = -40 ^{\circ}\text{C} \text{ to } +125 ^{\circ}\text{C};$	[3] _	500	mW

^[1] The minimum input voltage ratings may be exceeded if the input current ratings are observed.

^[2] The output voltage ratings may be exceeded if the output current ratings are observed.

^[3] Above 60 °C the value of Ptot derates linearly with 5.5 mW/K.

8. Recommended operating conditions

Table 5. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{CC}	supply voltage		1.65	-	3.6	V
		functional	1.2	-	3.6	V
V _I	input voltage		0	-	5.5	V
V _O	output voltage	output HIGH or LOW	0	-	V_{CC}	V
		output 3-state	0	-	5.5	V
T _{amb}	ambient temperature	in free air	-40	-	+125	°C
$\Delta t/\Delta V$	input transition rise and fall rate	$V_{CC} = 1.65 \text{ V to } 2.7 \text{ V}$	0	-	20	ns/V
		$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$	0	-	10	ns/V

9. Static characteristics

Table 6. Static characteristics

At recommended operating conditions. Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		-40	°C to +8	35 °C	-40 °C to	o +125 °C	Unit
				Min	Typ[1]	Max	Min	Max	
V_{IH}	HIGH-level	$V_{CC} = 1.2 \text{ V}$	1.	08	-	-	1.08	-	٧
	input voltage	V _{CC} = 1.65 V to 1.95 V	0.	65 × V _{CC}	-	-	$0.65 \times V_{CC}$	-	٧
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	1.	7	-	-	1.7	-	٧
		$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$	2.	0	-	-	2.0	-	V
V _{IL} LOW-level	V _{CC} = 1.2 V	-		-	0.12	-	0.12	٧	
	input voltage	$V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$	-		-	$0.35 \times V_{CC}$	-	$0.35 \times V_{CC}$	٧
	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	-		-	0.7	-	0.7	٧	
		$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$	-		-	0.8	-	0.8	٧
V _{OH} HIGH-level output voltage	$V_I = V_{IH}$ or V_{IL}								
	•	$I_O = -100 \mu A;$ $V_{CC} = 1.65 \text{ V to } 3.6 \text{ V}$	V	_{CC} – 0.2	-	-	$V_{CC}-0.3$	-	V
		$I_O = -2 \text{ mA}; V_{CC} = 1.65 \text{ V}$	1.	2	-	-	1.05	-	٧
		$I_O = -4 \text{ mA}; V_{CC} = 2.3 \text{ V}$	1.	7	-	-	1.55	-	٧
		$I_{O} = -6 \text{ mA}; V_{CC} = 2.7 \text{ V}$	2.	2	-	-	2.05	-	٧
		$I_O = -12 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.	2	-	-	2.0	-	٧
V _{OL}	LOW-level	$V_I = V_{IH}$ or V_{IL}							
	output voltage	$I_O = 100 \ \mu A;$ $V_{CC} = 1.65 \ V \ to \ 3.6 \ V$	-		-	0.2	-	0.3	V
		$I_O = 2 \text{ mA}; V_{CC} = 1.65 \text{ V}$	-		-	0.45	-	0.65	٧
		$I_O = 4 \text{ mA}; V_{CC} = 2.3 \text{ V}$	-		-	0.6	-	0.8	٧
		$I_O = 6 \text{ mA}; V_{CC} = 2.7 \text{ V}$	-		-	0.4	-	0.6	٧
		$I_O = 12 \text{ mA}; V_{CC} = 3.0 \text{ V}$	-		-	0.55	-	0.8	٧
l _l	input leakage current	$V_{CC} = 3.6 \text{ V};$ $V_{I} = 5.5 \text{ V or GND}$	-		±0.1	±5	-	±20	μА

74LVC_LVCH162244A

Table 6. Static characteristics ...continued

At recommended operating conditions. Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions			-40	°C to +8	35 °C		-40 °C to +125 °C		
					Min	Typ[1]	Max		Min	Max	
l _{OZ}	OFF-state output current	$V_I = V_{IH}$ or V_{IL} ; $V_{CC} = 3.6$ V; $V_O = 5.5$ V or GND;	[2]	-		±0.1	±5	-		±20	μΑ
l _{OFF}	power-off leakage current	$V_{CC} = 0 \text{ V}; V_{I} \text{ or } V_{O} = 5.5 \text{ V}$		-		±0.1	±10	-		±20	μА
I _{CC}	supply current	$V_{CC} = 3.6 \text{ V};$ $V_{I} = V_{CC} \text{ or GND}; I_{O} = 0 \text{ A}$		-		0.1	20	-		80	μА
ΔI_{CC}	additional supply current	per input pin; $V_{CC} = 2.7 \text{ V to } 3.6 \text{ V};$ $V_{I} = V_{CC} - 0.6 \text{ V};$ $I_{O} = 0 \text{ A}$		-		5	500	-		5000	μА
Cı	input capacitance	$V_{CC} = 0 \text{ V to } 3.6 \text{ V};$ $V_{I} = \text{GND to } V_{CC}$		-		5.0	-	-		-	pF
I _{BHL}	bus hold	$V_{CC} = 1.65; V_I = 0.58 V$	[3][4]		10	-	-		10	-	μΑ
	LOW current	$V_{CC} = 2.3; V_I = 0.7 V$			30	-	-		25	-	μΑ
		$V_{CC} = 3.0; V_I = 0.8 V$			75	-	-		60	-	μΑ
I _{BHH}	bus hold	$V_{CC} = 1.65; V_I = 1.07 V$	[3][4]		-10	-	-		-10	-	μΑ
	HIGH current	$V_{CC} = 2.3; V_I = 1.7 V$			-30	-	-		-25	-	μΑ
		$V_{CC} = 3.0; V_I = 2.0 V$			−75	-	-		-60	-	μΑ
I_{BHLO}	bus hold	$V_{CC} = 1.95 \text{ V}$	[3][5]		200	-	-		200	-	μΑ
	LOW overdrive	$V_{CC} = 2.7 \text{ V}$			300	-	-		300	-	μΑ
	current	$V_{CC} = 3.6 \text{ V}$			500	-	-		500	-	μА
I _{BHHO}	bus hold	V _{CC} = 1.95 V	[3][5]		-200	-	-		-200	-	μΑ
	HIGH overdrive	V _{CC} = 2.7 V			-300	-	-		-300	-	μΑ
	current	V _{CC} = 3.6 V			-500	-	-		-500	-	μΑ

^[1] All typical values are measured at V_{CC} = 3.3 V and T_{amb} = 25 °C.

^[2] The bus hold circuit is switched off when $V_I > V_{CC}$ allowing 5.5 V on the input terminal.

^[3] Valid for data inputs only. Control inputs do not have a bus hold circuit.

^[4] The specified sustaining current at the data input holds the input below the specified V_I level.

^[5] The specified overdrive current at the data input forces the data input to the opposite logic input state.

10. Dynamic characteristics

Table 7. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V). For test circuit see Figure 7.

Symbol	Parameter	Conditions		-40	°C to +8	5 °C	-40 °C to +125 °C		Unit
				Min	Typ[2]	Max	Min	Max	
t _{pd}	propagation	nAn to nYn; see Figure 5	[1]						
	delay	V _{CC} = 1.2 V		-	11.0	-	-	-	ns
		V _{CC} = 1.65 V to 1.95 V		1.5	6.0	15.0	1.5	17.2	ns
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		1.0	3.2	7.4	1.0	8.2	ns
		V _{CC} = 2.7 V		1.0	3.3	6.7	1.0	8.5	ns
		V _{CC} = 3.0 V to 3.6 V		1.0	2.7	5.8	1.0	7.5	ns
t _{en}	enable time	nOE to nYn; see Figure 6	[1]						
		V _{CC} = 1.2 V		-	15.0	-	-	-	ns
		V _{CC} = 1.65 V to 1.95 V		1.7	6.8	15.3	1.7	17.7	ns
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		1.5	3.8	8.0	1.5	8.9	ns
		V _{CC} = 2.7 V		1.5	4.2	7.6	1.5	9.5	ns
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$		1.0	3.1	6.0	1.0	7.5	ns
t _{dis}	disable time	nOE to nYn; see Figure 6	[1]						
		V _{CC} = 1.2 V		-	10.0	-	-	-	ns
		V _{CC} = 1.65 V to 1.95 V		2.2	3.9	8.2	2.2	9.5	ns
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		0.5	2.1	4.4	0.5	5.0	ns
		V _{CC} = 2.7 V		1.5	3.1	4.7	1.5	6.0	ns
		V _{CC} = 3.0 V to 3.6 V		1.5	2.8	4.5	1.5	6.0	ns
C_{PD}	power	per input; $V_I = GND$ to V_{CC}	[3]						
	dissipation	V _{CC} = 1.65 V to 1.95 V		-	4.8	-	-	-	pF
	capacitance	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		-	8.3	-	-	-	pF
		V _{CC} = 3.0 V to 3.6 V		-	11.4	-	-	-	pF

^[1] t_{pd} is the same as t_{PLH} and t_{PHL} .

$$P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma (C_L \times V_{CC}^2 \times f_o)$$
 where:

 f_i = input frequency in MHz; f_o = output frequency in MHz

 C_L = output load capacitance in pF

V_{CC} = supply voltage in Volts

N = number of inputs switching

 $\Sigma(C_L \times V_{CC}^2 \times f_o)$ = sum of the outputs.

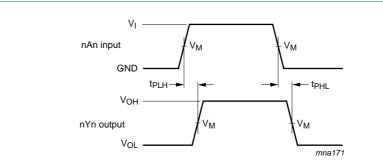
 t_{en} is the same as t_{PZL} and $t_{\text{PZH}}.$

 t_{dis} is the same as t_{PLZ} and t_{PHZ} .

^[2] Typical values are measured at T_{amb} = 25 °C and V_{CC} = 1.2 V, 1.8 V, 2.5 V, 2.7 V and 3.3 V respectively.

^[3] C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

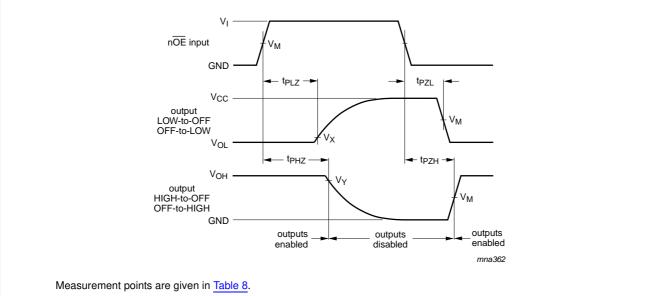
11. Waveforms



Measurement points are given in Table 8.

Logic levels: V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.

Fig 5. The input (nAn) to output (nYn) propagation delays



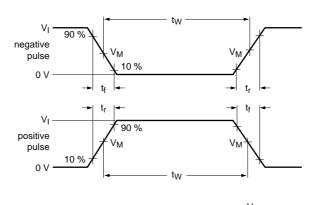
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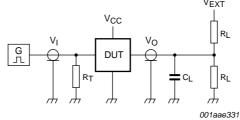
3-state enable and disable times.

Table 8. Measurement points

Supply voltage	V _M	Input		Output		
V _{CC}		VI	$t_r = t_f$	V _X	V _Y	
1.2 V	$0.5 \times V_{CC}$	V _{CC}	\leq 2.5 ns	$V_{OL} + 0.15 V$	$V_{OH}-0.15\ V$	
1.65 V to 1.95 V	$0.5 \times V_{CC}$	V _{CC}	≤ 2.5 ns	V _{OL} + 0.15 V	$V_{OH}-0.15\ V$	
2.3 V to 2.7 V	$0.5 \times V_{CC}$	V _{CC}	≤ 2.5 ns	V _{OL} + 0.15 V	$V_{OH}-0.15\ V$	
2.7 V	1.5 V	2.7 V	≤ 2.5 ns	V_{OL} + 0.3 V	$V_{OH}-0.3\ V$	
3.0 V to 3.6 V	1.5 V	2.7 V	≤ 2.5 ns	V_{OL} + 0.3 V	$V_{OH}-0.3\ V$	

Fig 6.





Test data is given in Table 9.

Definitions for test circuit:

R_L = Load resistance.

C_L = Load capacitance including jig and probe capacitance.

 R_T = Termination resistance should be equal to output impedance Z_0 of the pulse generator.

V_{EXT} = External voltage for measuring switching times.

Fig 7. Test circuit for measuring switching times

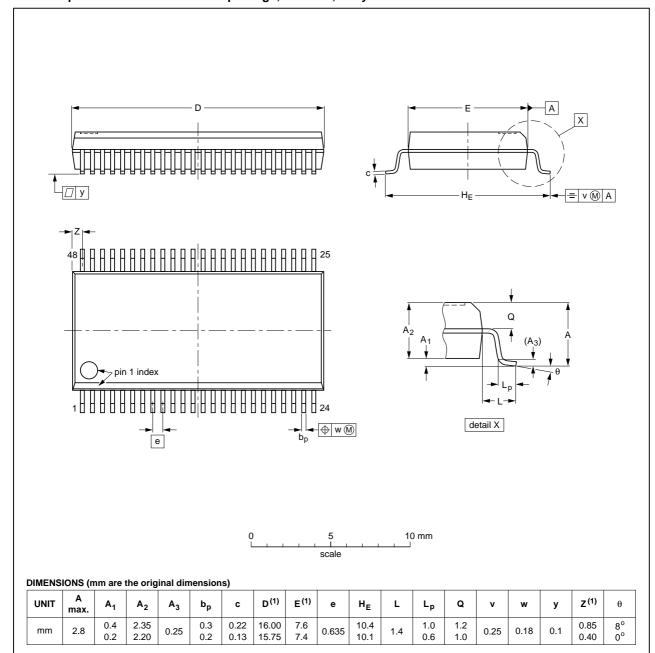
Table 9. Test data

Supply voltage	Input		Load		V _{EXT}		
	VI	t _r , t _f	CL	RL	t _{PLH} , t _{PHL}	t_{PLZ} , t_{PZL}	t _{PHZ} , t _{PZH}
1.2 V	V_{CC}	≤ 2 ns	30 pF	1 kΩ	open	$2\times V_{CC}$	GND
1.65 V to 1.95 V	V_{CC}	≤ 2 ns	30 pF	1 kΩ	open	$2\times V_{CC}$	GND
2.3 V to 2.7 V	V_{CC}	≤ 2 ns	30 pF	500Ω	open	$2\times V_{CC}$	GND
2.7 V	2.7 V	≤ 2.5 ns	50 pF	500Ω	open	$2\times V_{CC}$	GND
3.0 V to 3.6 V	2.7 V	≤ 2.5 ns	50 pF	500Ω	open	$2\times V_{\text{CC}}$	GND

12. Package outline

SSOP48: plastic shrink small outline package; 48 leads; body width 7.5 mm

SOT370-1



Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

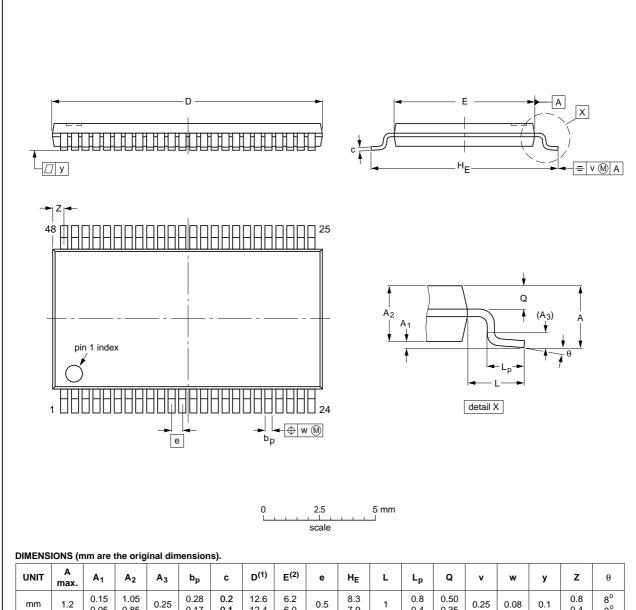
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Fig 8. Package outline SOT370-1 (SSOP48)

74LVC_LVCH162244A

TSSOP48: plastic thin shrink small outline package; 48 leads; body width 6.1 mm

SOT362-1



UNIT	A max.	A ₁	A ₂	A ₃	bp	С	D ⁽¹⁾	E ⁽²⁾	е	HE	L	Lp	Q	v	w	у	Z	θ	
mm	1.2	0.15 0.05	1.05 0.85	0.25	0.28 0.17	0.2 0.1	12.6 12.4	6.2 6.0	0.5	8.3 7.9	1	0.8 0.4	0.50 0.35	0.25	0.08	0.1	0.8 0.4	8° 0°	

Notes

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

VERSION IEC JEDEC JEITA PROJECTION SOT362-1 MO-153 MO-153	OUTLINE		REFER	EUROPEAN	ISSUE DATE			
SO 1362-1 MO-153 ++ #+\+	VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE	
03-02-1	SOT362-1		MO-153				99-12-27 03-02-19	

Package outline SOT362-1 (TSSOP48) Fig 9.

74LVC_LVCH162244A

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13. Abbreviations

Table 10. Abbreviations

Acronym	Description
CDM	Charged Device Model
CMOS	Complementary Metal Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
НВМ	Human Body Model
MM	Machine Model
TTL	Transistor-Transistor Logic

14. Revision history

Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74LVC_LVCH162244A v.6	20111216	Product data sheet	-	74LVC_LVCH162244A v.5
Modifications:		propagation delay value ns to 17.2 ns	for V _{CC} =	1.65 V to 1.95 V at +125 °C changed
	 Maximum 16.1 ns to 		_{CC} = 1.65 V	to 1.95 V at +125 °C changed from
	Maximum 8.7 ns to 9		_{CC} = 1.65 \	/ to 1.95 V at +125 °C changed from
74LVC_LVCH162244A v.5	20111108	Product data sheet	-	74LVC_LVCH162244A v.4
Modifications:		t of this document has b of NXP Semiconductors		gned to comply with the new identity
	 Legal texts 	s have been adapted to t	he new co	mpany name where appropriate.
	• <u>Table 5, Ta</u>	able 6, <u>Table 7</u> and <u>Table</u>	9: values	added for lower voltage ranges.
74LVC_LVCH162244A v.4	20031212	Product specification	-	74LVC_H162244A v.3
74LVC_H162244A v.3	19980217	Product specification	-	74LVC162244A_LVCH162244A v.3
74LVC162244A_LVCH162244A v.3	19980217	Product specification	-	74LVC162244A v.2
74LVC162244A v.2	19970801	Product specification	-	74LVC162244A v.1
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74LVC162244A; 74LVCH162244A

16-bit buffer/line driver; 30 Ω resistors; 5 V tolerance; 3-state

15. Legal information

15.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design
- [2] The term 'short data sheet' is explained in section "Definitions"
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16-bit buffer/line driver; 30 Ω resistors; 5 V tolerance; 3-state

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